

# MAC4M, MAC4N

Preferred Device

## Triacs

### Silicon Bidirectional Thyristors

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

- Blocking Voltage to 800 Volts
- On-State Current Rating of 4.0 Amperes RMS at 100°C
- Uniform Gate Trigger Currents in Three Modes
- High Immunity to dv/dt — 500 V/μs minimum at 125°C
- Minimizes Snubber Networks for Protection
- High Surge Current Capability – 40 Amperes
- Industry Standard TO-220AB Package
- High Commutating di/dt — 6.0 A/ms minimum at 125°C
- Operational in Three Quadrants: Q1, Q2, and Q3
- Device Marking: Logo, Device Type, e.g., MAC4M, Date Code

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage <sup>(1)</sup> (T <sub>J</sub> = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)  MAC4M MAC4N	V <sub>DRM</sub> , V <sub>RRM</sub>	600 800	Volts
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T <sub>C</sub> = 100°C)	I <sub>T(RMS)</sub>	4.0	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>J</sub> = 125°C)	I <sub>TSM</sub>	40	Amps
Circuit Fusing Consideration (t = 8.33 ms)	I <sup>2</sup> t	6.6	A <sup>2</sup> sec
Peak Gate Power (Pulse Width ≤ 1.0 μs, T <sub>C</sub> = 100°C)	P <sub>GM</sub>	0.5	Watt
Average Gate Power (t = 8.3 ms, T <sub>C</sub> = 100°C)	P <sub>G(AV)</sub>	0.1	Watt
Operating Junction Temperature Range	T <sub>J</sub>	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

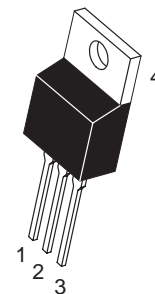
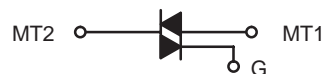
(1) V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



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**TRIACS**  
**4 AMPERES RMS**  
**600 thru 800 VOLTS**



**TO-220AB**  
**CASE 221A**  
**STYLE 4**

#### PIN ASSIGNMENT

1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

#### ORDERING INFORMATION

Device	Package	Shipping
MAC4M	TO220AB	50 Units/Rail
MAC4N	TO220AB	50 Units/Rail

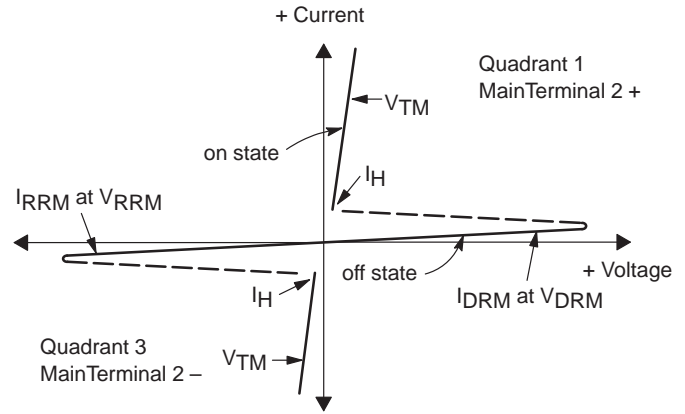
**Preferred** devices are recommended choices for future use and best overall value.



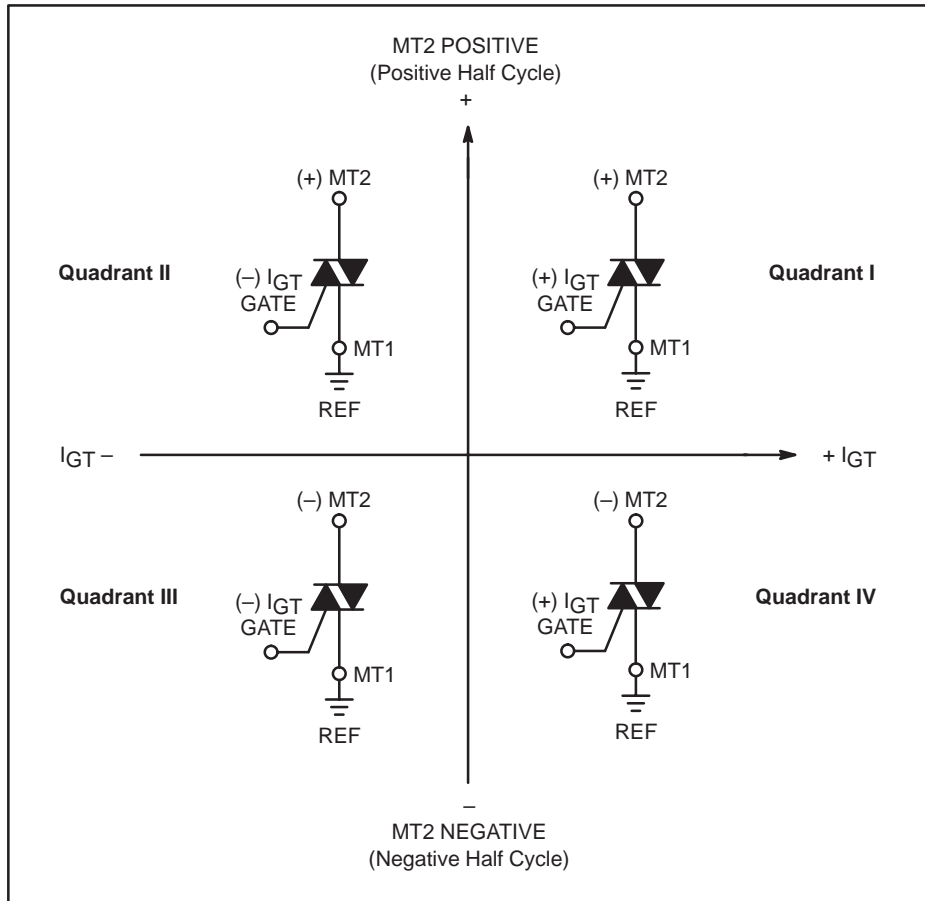
# MAC4M, MAC4N

## Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current

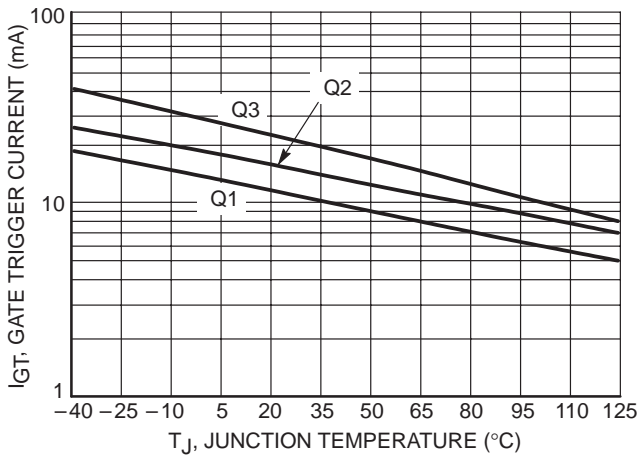


### Quadrant Definitions for a Triac

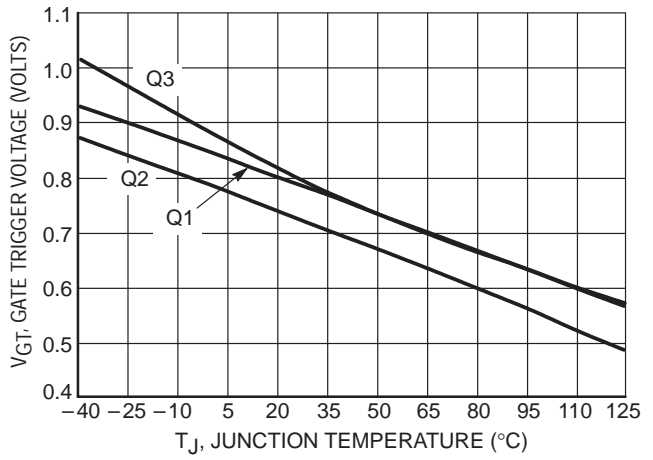


All polarities are referenced to MT1.  
 With in-phase signals (using standard AC lines) quadrants I and III are used.

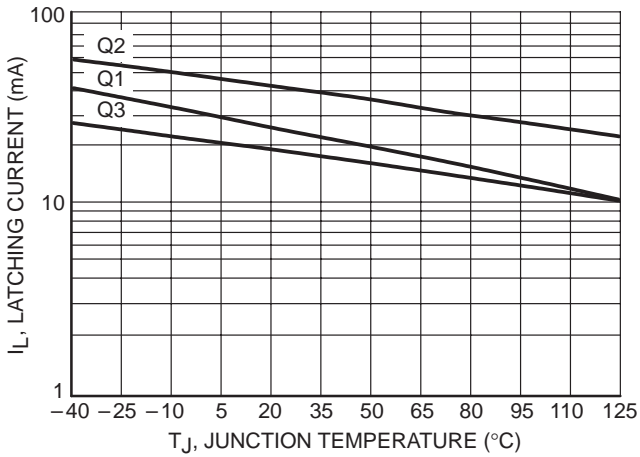
# MAC4M, MAC4N



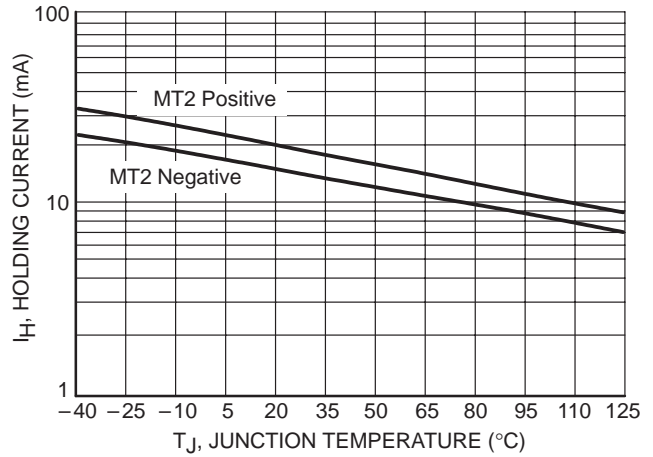
**Figure 1. Typical Gate Trigger Current versus Junction Temperature**



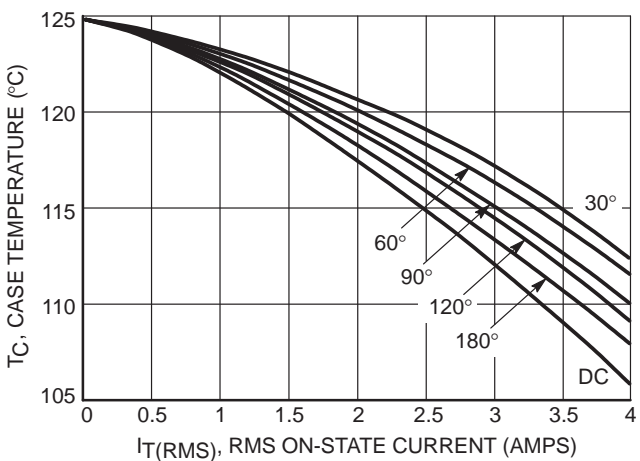
**Figure 2. Typical Gate Trigger Voltage versus Junction Temperature**



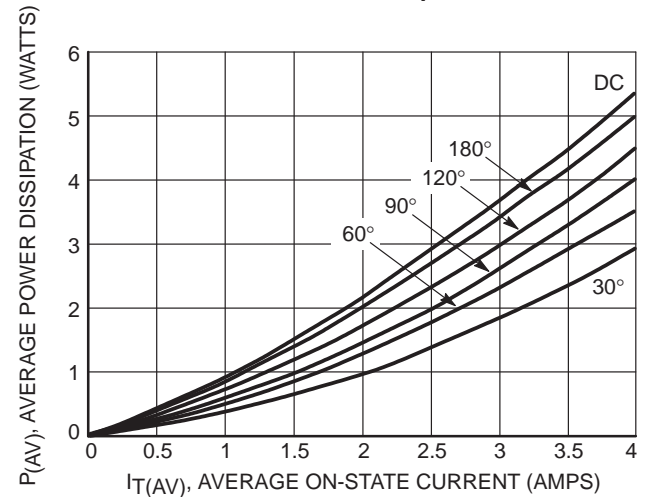
**Figure 3. Typical Latching Current versus Junction Temperature**



**Figure 4. Typical Holding Current versus Junction Temperature**



**Figure 5. Typical RMS Current Derating**



**Figure 6. On-State Power Dissipation**

# MAC4M, MAC4N

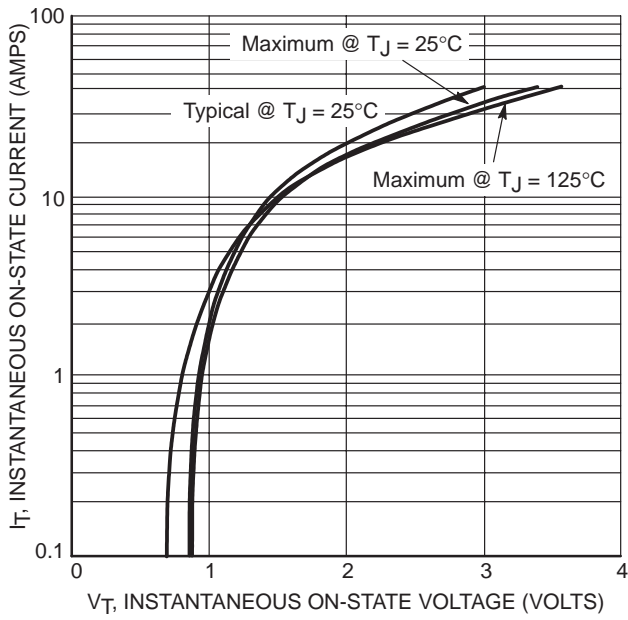


Figure 7. Typical On-State Characteristics

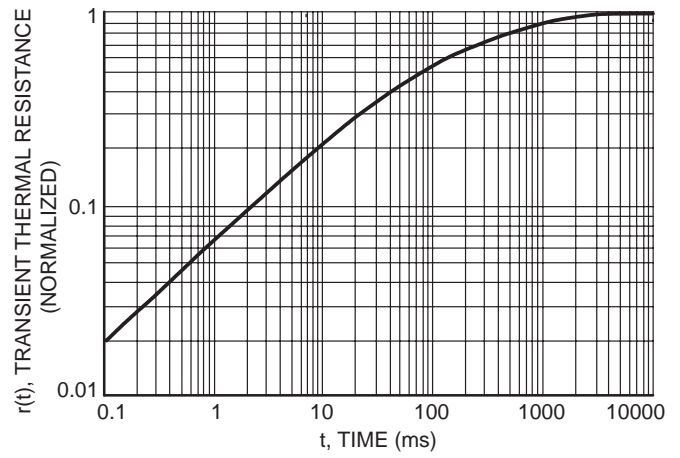
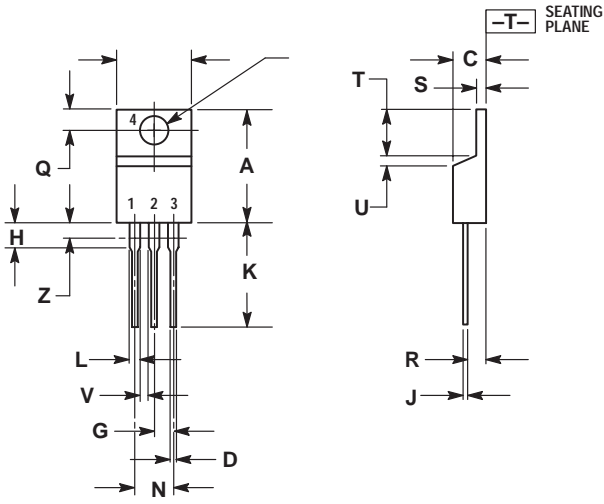


Figure 8. Typical Thermal Response

# MAC4M, MAC4N

## PACKAGE DIMENSIONS

TO-220AB  
CASE 221A-09  
ISSUE Z



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

- STYLE 4:  
PIN 1. MAIN TERMINAL 1  
2. MAIN TERMINAL 2  
3. GATE  
4. MAIN TERMINAL 2

## Notes

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